



# Target Specification

## High Precision Hall-Effect Switch

### **TLE4906H**

### Version 1.6

## Features

- 2.7V to 24V supply voltage operation
- Operation from unregulated power supply
- High sensitivity and high stability of the magnetic switching points
- High resistance to mechanical stress by Active Error Compensation
- Reverse battery protection (-18V)
- Superior temperature stability
- Peak temperatures up to 195°C without damage
- Low jitter (typ. 1µs)
- High ESD performance (±6kV HBM)
- Digital output signal
- Unipolar version
- SMD package P-SC59-3-2 (SOT-23 compatible)

Type	Ordering Code	Package
TLE4906H	t.b.d.	P-SC59-3-2

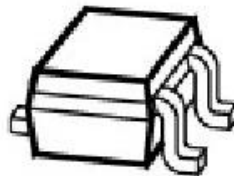


Figure 1: P-SC59-3-2

## Functional Description

The TLE4906H is an integrated circuit Hall-effect sensor designed specifically for highly accurate applications. Precise magnetic switching points and high temperature stability are achieved by active compensation circuits and chopper techniques on chip.

## Circuit Description

The chopped Hall IC Switch comprises a Hall probe, bias generator, compensation circuits, oscillator and output transistor.

The bias generator provides currents for the Hall probe and the active circuits. Compensation circuits stabilize the temperature behavior and reduce technology variations.

The Active Error Compensation rejects offsets in signal stages and the influence of mechanical stress to the Hall probe caused by molding and soldering processes and other thermal stresses in the package. This chopper technique together with the threshold generator and the comparator ensure high accurate magnetic switching points.

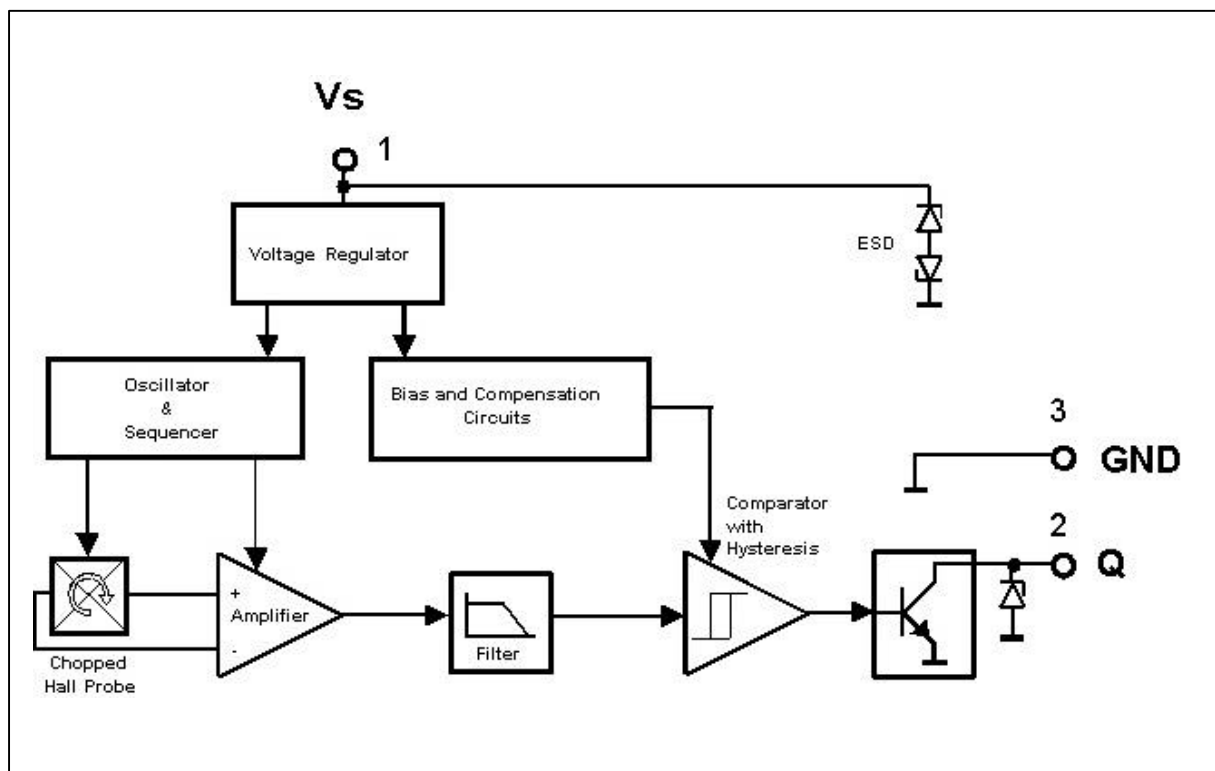


Figure 2: Block Diagram TLE4906H

## Pin Configuration

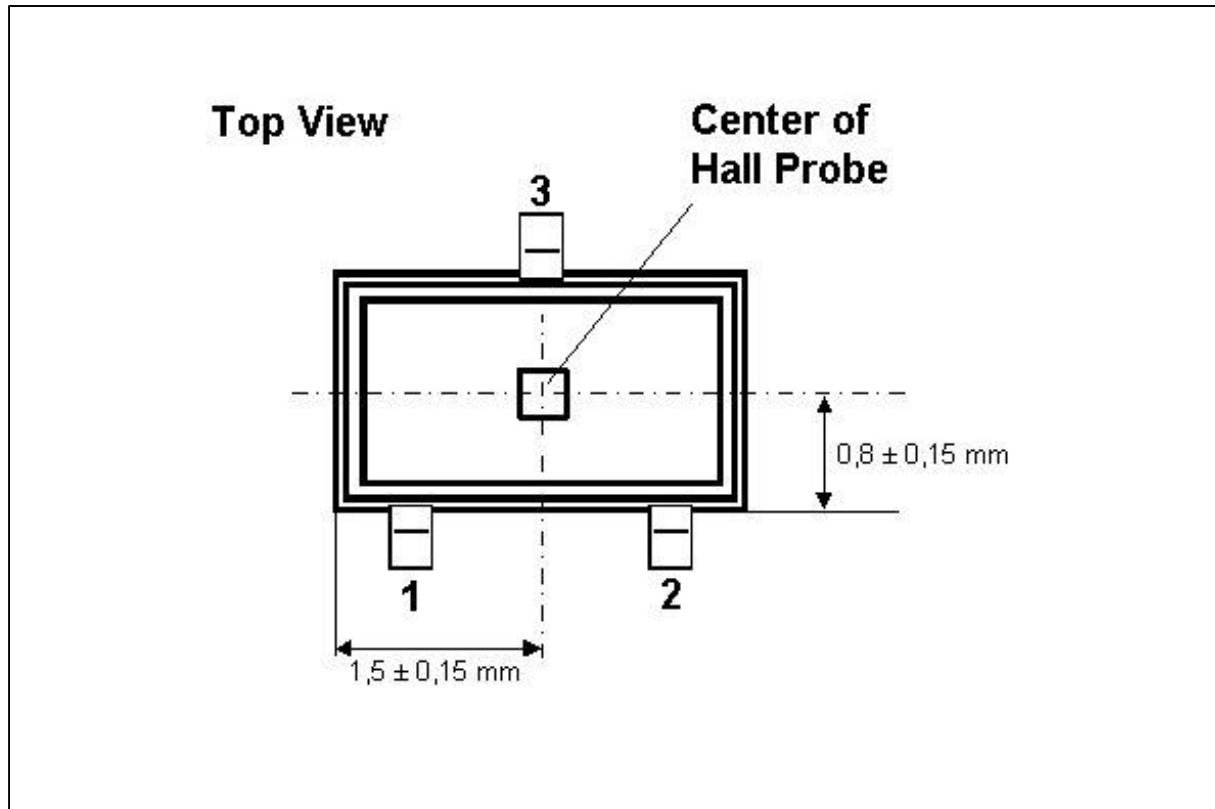


Figure 3: Pin Configuration TLE4906H (SOT-23 pin compatible)

## Pin Definition and Functions

Pin	Symbol	Function
1	$V_S$	Supply voltage
2	Q	Output
3	GND	Ground

## Absolute Maximum Ratings

$T_j = -40$  to  $150^{\circ}\text{C}$

Parameter	Symbol	min.	max.	Unit	Conditions
Supply Voltage	$V_S$	-18 -18 -18	18 24 26	V	for 1h, $R_S \geq 200\ \Omega$ for 5min, $R_S \geq 200\ \Omega$
Supply Current through protection device	$I_S$	-50	+50	mA	
Output Voltage	$V_Q$	-0.7 -0.7	18 26	V	for 5 min @ 1.2 k $\Omega$ pull up
Continuous Output Current	$I_Q$	-50	+50	mA	
Junction Temperature	$T_j$	-	155 165 175 195	$^{\circ}\text{C}$	for 2000 h (not additive) for 1000 h (not additive) for 168 h (not additive) for 3x1 h (additive)
Storage Temperature	$T_S$	-40	150	$^{\circ}\text{C}$	
Magnetic Flux Density	B	-	unlimit.	mT	

Note: Stresses above those listed here may cause permanent damage to the device.

Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ESD Protection

Human Body Model (HBM) tests according to:

EOS/ESD Association Standard S5.1-1993 and Mil. Std. 883D method 3015.7

Parameter	Symbol	max.	Unit	Conditions
ESD Voltage	$U_{\text{ESD}}$	$\pm 6$	kV	HBM, $R = 1.500\ \Omega$ , $C = 100\text{pF}$ ; $T_A = 25^{\circ}\text{C}$

## Operating Range

Parameter	Symbol	min.	typ.	max.	Unit	Conditions
Supply Voltage	$V_S$	2.7	-	18 24 26	V	1h with $R_S \geq 200\ \Omega$ 5min with $R_S \geq 200\ \Omega$
Output Voltage	$V_Q$	-0.7	-	18	V	
Junction Temperature	$T_j$	-40	-	150 175	$^{\circ}\text{C}$	for 168 h
Output Current	$I_Q$	0	-	20	mA	

## AC/DC Characteristics

over operating range, unless otherwise specified. Typical values correspond to  $V_S=12V$  and  $T_A=25^\circ C$ .

Parameter	Symbol	min.	typ.	max.	Unit	Conditions
Supply Current	$I_S$	2	4	6	mA	$V_S = 2.7V \dots 18V$
Reverse Current	$I_{SR}$	0	0.2	1	mA	$V_Q=12V$ ; $V_S=-18V$
Output Saturation Voltage	$V_{QSAT}$	-	0.3	0.6	V	$I_Q=20mA$
Output Leakage Current	$I_{LEAK}$	-	0.05	10	$\mu A$	$V_Q=18V$
Output Fall Time	$t_f$	-	0.02	1	$\mu s$	$R_L = 1.2 k\Omega$ ; $C_L=50pF$
Output Rise Time	$t_r$	-	0.4	1	$\mu s$	$R_L = 1.2 k\Omega$ ; $C_L=50pF$
Chopper Frequency	$f_{OSC}$	-	320	-	kHz	
Switching Frequency	$f_{SW}$	-	-	30	kHz	Typ. value for $B_{PP}=1.5 \cdot B_{HYS}$
				t.b.d.		
Delay Time <sup>1)</sup>	$t_d$	-	13	20	$\mu s$	
				t.b.d.		
Output Jitter <sup>2)</sup>	$t_{QJ}$	-	1	-	$\mu s_{RMS}$	Typ. Value for Square-Wave Signal 1kHz
Repeatability of magnetic thresholds <sup>3)</sup>	$B_{REP}$	-	20	-	$\mu T_{RMS}$	Typ. Value for $\Delta B/\Delta t > 12mT/ms$
Power-On Time <sup>4)</sup>	$t_{PON}$	-	13	30	$\mu s$	$V_S \geq 2.7V$
Thermal Resistance <sup>5)</sup>	$R_{thJA}$	-	-	35	K/W	

<sup>1)</sup> Systematic delay between magnetic threshold reached and output switching.

<sup>2)</sup> Jitter is the unpredictable deviation of the output switching delay.

<sup>3)</sup>  $B_{REP}$  is equivalent to the noise constant.

<sup>4)</sup> Time from applying  $V_S \geq 2.7V$  to the sensor until the output state is valid.

<sup>5)</sup> Thermal resistance from junction to ambient.

e.g. for  $V_S=2.7V$ ,  $I_{Smax}=6mA$ ,  $V_{QSAT}=0.4V$  and  $I_Q=20mA \Rightarrow$  Power Dissipation  $P_{dis}=24.2mW$ .

In  $T_A = T_j - (R_{thJA} \cdot P_{dis}) = 175^\circ C - (35 K/W \cdot 0.0242 W) \Rightarrow T_A = 174.2^\circ C$

## Magnetic Characteristics

over operating range, unless otherwise specified. Typical values correspond to  $V_S=12V$ .

Parameter	Symbol	$T_j [^\circ C]$	min.	typ.	max.	Unit	Conditions
Operate Point TLE4906H	$B_{OP}$	-40 25 150	6.7 6.5 6.2	10.3 10.0 9.5	13.9 13.5 12.9	mT	
Release Point TLE4906H	$B_{RP}$	-40 25 150	5.2 5.0 4.7	8.7 8.5 8.1	12.3 12.0 11.4	mT	
Hysteresis TLE4906H	$B_{HYS}$	-40 25 150	- 0.7 -	- 1.5 -	- 3.0 -	mT	
Temperature Compensation of Magnetic Thresholds	TC		-	-350	-	ppm/ $^\circ C$	

Positive magnetic fields related with south pole of magnet to the branded side of package.

Note: Typical characteristics specify mean values expected over the production spread.

## Timing Diagram

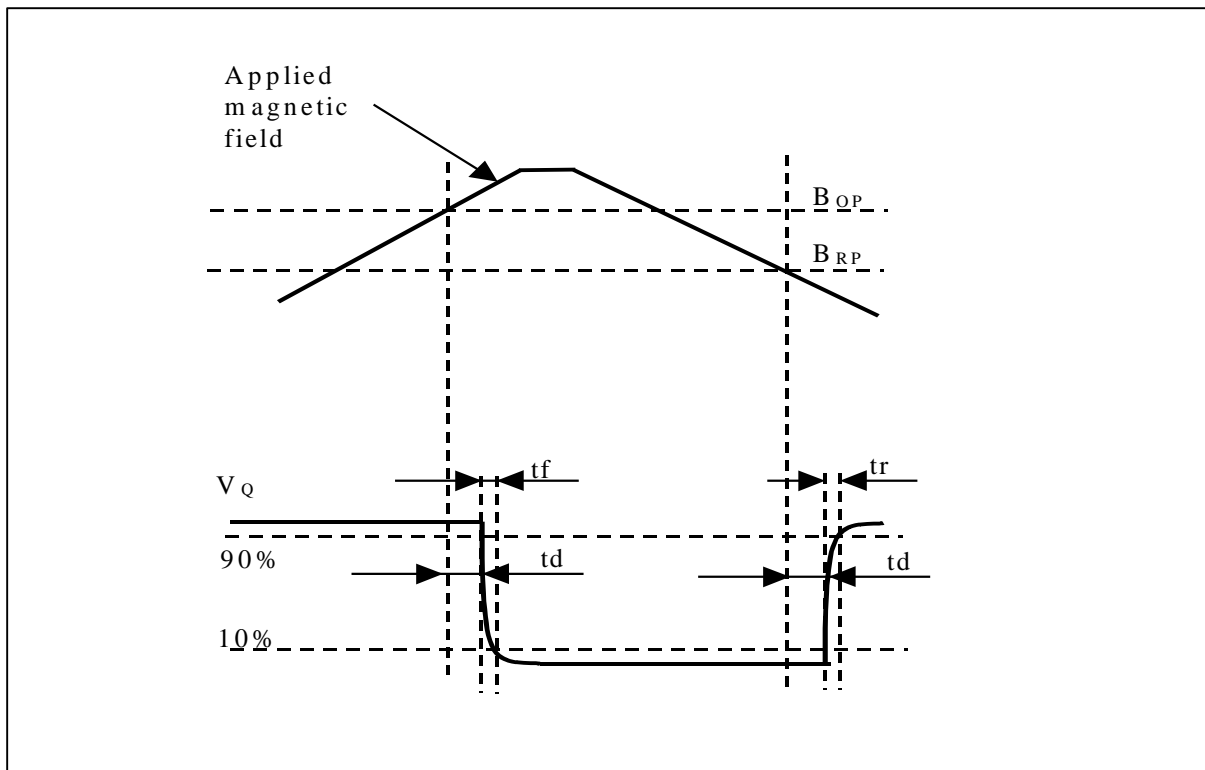


Figure 4: Timing definition of TLE4906H

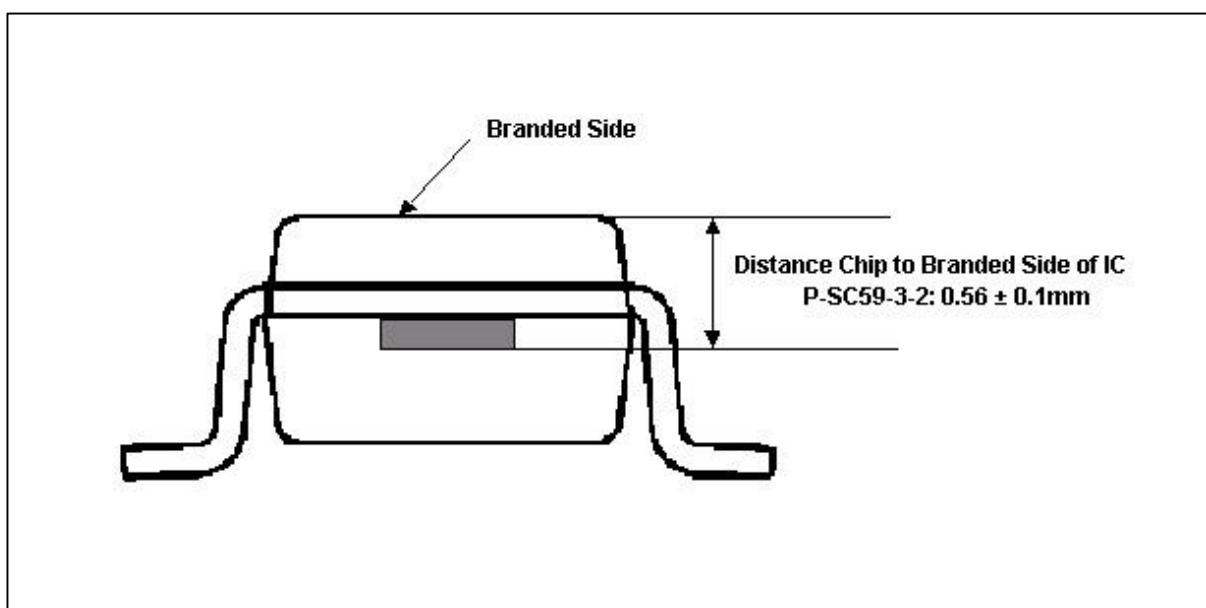


Figure 5: Distance from package to die

Technical drawing of a mechanical part, showing front and side views with dimensions and tolerances.

**Front View Dimensions:**

- Overall width:  $3 \pm 0.1$
- Distance between mounting holes:  $0.95$
- Mounting hole diameter:  $\varnothing 0.1(M)$
- Distance from mounting hole to centerline:  $(0.55)$
- Overall height:  $2.8^{+0.2}_{-0.1}$
- Bottom flange width:  $0.4^{+0.05}_{-0.10}$
- Bottom flange thickness:  $(3x)$
- Bottom flange mounting hole diameter:  $\varnothing 0.1(M)$

**Side View Dimensions:**

- Top flange thickness:  $0.15^{+0.10}_{-0.05}$
- Top flange angle:  $0^\circ \dots 8^\circ \max.$
- Top flange mounting hole diameter:  $\varnothing 0.1$
- Top flange width:  $0.45 \pm 0.15$
- Top flange height:  $1.6^{+0.15}_{-0.30}$
- Top flange thickness:  $0.15 \max.$
- Top flange width:  $1.1 \pm 0.1$

Figure 7: Foot print TLE4906H



	High Precision Hall-Effect Switch Target Specification <b>TLE4906H</b>	Version 1.6 Date: 2003/02/21 Page 9 of 9
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<b>TLE4906H</b>	
<b>Revision History: 2003-02-21</b>	
Previous Version:	
Page	Subjects (major changes since last revision)

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